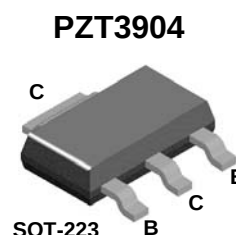
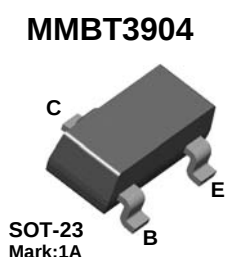


2N3904 / MMBT3904 / PZT3904

NPN General Purpose Amplifier

Features

- This device is designed as a general purpose amplifier and switch.
- The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.



Absolute Maximum Ratings* $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	40	V
V_{CBO}	Collector-Base Voltage	60	V
V_{EBO}	Emitter-Base Voltage	6.0	V
I_C	Collector Current - Continuous	200	mA
T_J, T_{stg}	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max.			Units
		2N3904	*MMBT3904	**PZT3904	
P_D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	1,000 8.0	mW mW/ $^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	$^\circ\text{C}/\text{W}$

* Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06".

** Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm².

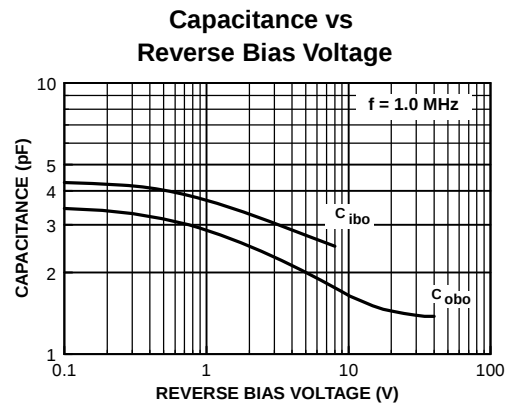
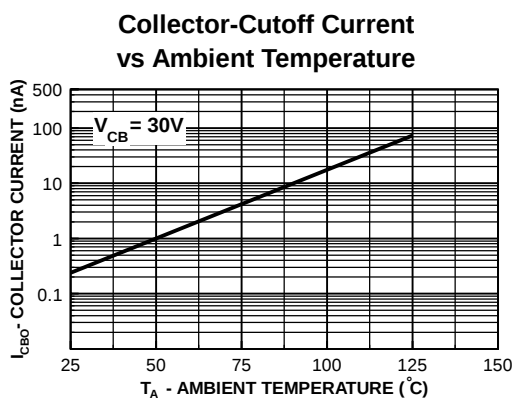
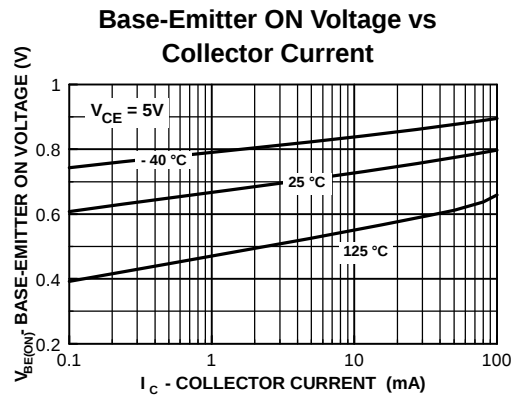
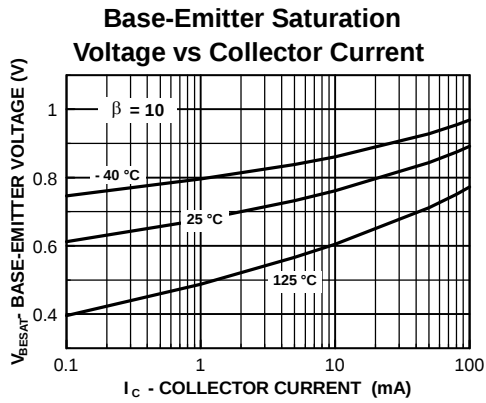
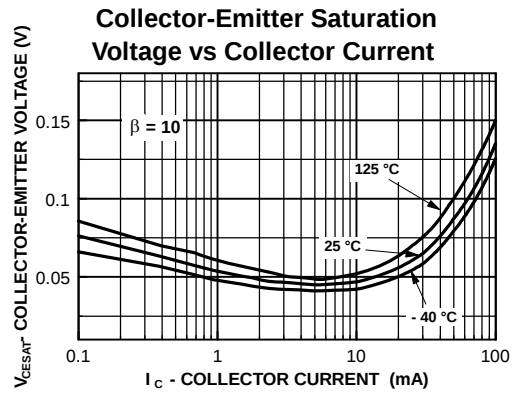
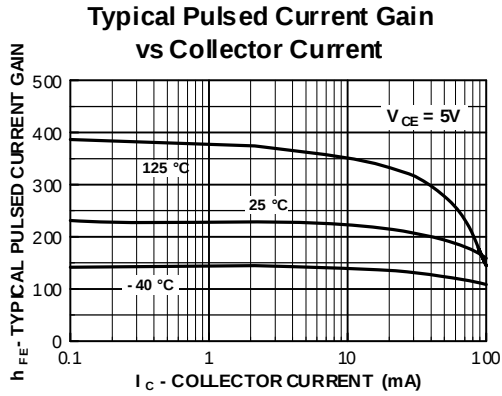
Electrical Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 1.0\text{mA}, I_B = 0$	40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 10\mu\text{A}, I_E = 0$	60		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10\mu\text{A}, I_C = 0$	6.0		V
I_{BL}	Base Cutoff Current	$V_{CE} = 30\text{V}, V_{EB} = 3\text{V}$		50	nA
I_{CEX}	Collector Cutoff Current	$V_{CE} = 30\text{V}, V_{EB} = 3\text{V}$		50	nA
ON CHARACTERISTICS*					
h_{FE}	DC Current Gain	$I_C = 0.1\text{mA}, V_{CE} = 1.0\text{V}$ $I_C = 1.0\text{mA}, V_{CE} = 1.0\text{V}$ $I_C = 10\text{mA}, V_{CE} = 1.0\text{V}$ $I_C = 50\text{mA}, V_{CE} = 1.0\text{V}$ $I_C = 100\text{mA}, V_{CE} = 1.0\text{V}$	40 70 100 60 30	300	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 10\text{mA}, I_B = 1.0\text{mA}$ $I_C = 50\text{mA}, I_B = 5.0\text{mA}$		0.2 0.3	V V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 10\text{mA}, I_B = 1.0\text{mA}$ $I_C = 50\text{mA}, I_B = 5.0\text{mA}$	0.65	0.85 0.95	V V
SMALL SIGNAL CHARACTERISTICS					
f_T	Current Gain - Bandwidth Product	$I_C = 10\text{mA}, V_{CE} = 20\text{V},$ $f = 100\text{MHz}$	300		MHz
C_{obo}	Output Capacitance	$V_{CB} = 5.0\text{V}, I_E = 0,$ $f = 1.0\text{MHz}$		4.0	pF
C_{ibo}	Input Capacitance	$V_{EB} = 0.5\text{V}, I_C = 0,$ $f = 1.0\text{MHz}$		8.0	pF
NF	Noise Figure	$I_C = 100\mu\text{A}, V_{CE} = 5.0\text{V},$ $R_S = 1.0\text{k}\Omega,$ $f = 10\text{Hz to } 15.7\text{kHz}$		5.0	dB
SWITCHING CHARACTERISTICS					
t_d	Delay Time	$V_{CC} = 3.0\text{V}, V_{BE} = 0.5\text{V}$		35	ns
t_r	Rise Time	$I_C = 10\text{mA}, I_{B1} = 1.0\text{mA}$		35	ns
t_s	Storage Time	$V_{CC} = 3.0\text{V}, I_C = 10\text{mA},$		200	ns
t_f	Fall Time	$I_{B1} = I_{B2} = 1.0\text{mA}$		50	ns

* Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2.0\%$ **Ordering Information**

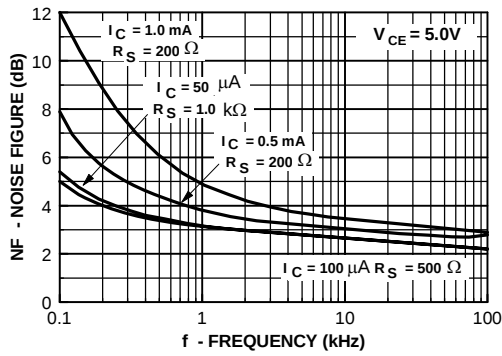
Part Number	Marking	Package	Packing Method	Pack Qty
2N3904BU	2N3904	TO-92	BULK	10000
2N3904TA	2N3904	TO-92	AMMO	2000
2N3904TAR	2N3904	TO-92	AMMO	2000
2N3904TF	2N3904	TO-92	TAPE REEL	2000
2N3904TFR	2N3904	TO-92	TAPE REEL	2000
MMBT3904	1A	SOT-23	TAPE REEL	3000
MMBT3904_D87Z	1A	SOT-23	TAPE REEL	10000
PZT3904	3904	SOT-223	TAPE REEL	2500

Typical Performance Characteristics

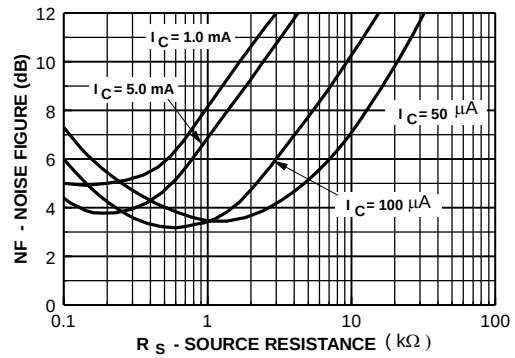


Typical Performance Characteristics (continued)

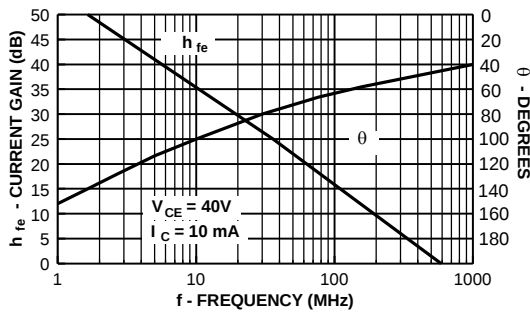
Noise Figure vs Frequency



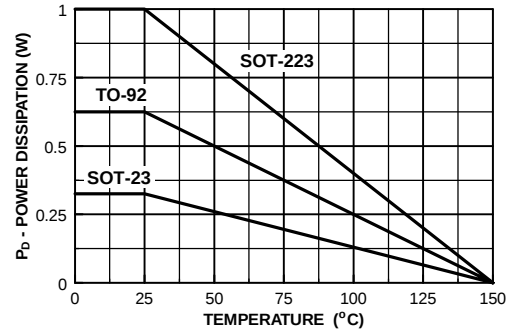
Noise Figure vs Source Resistance



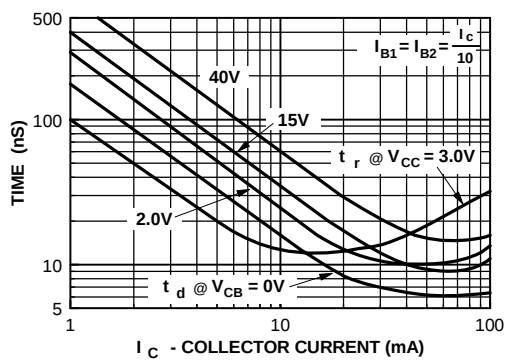
Current Gain and Phase Angle vs Frequency



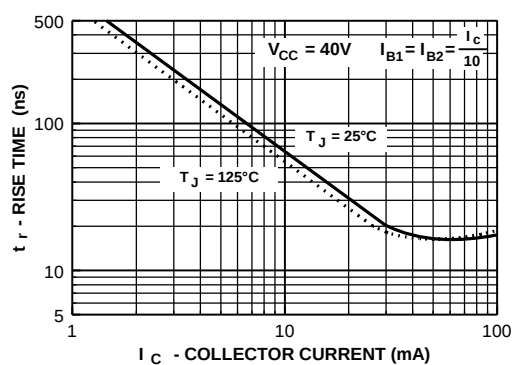
Power Dissipation vs Ambient Temperature



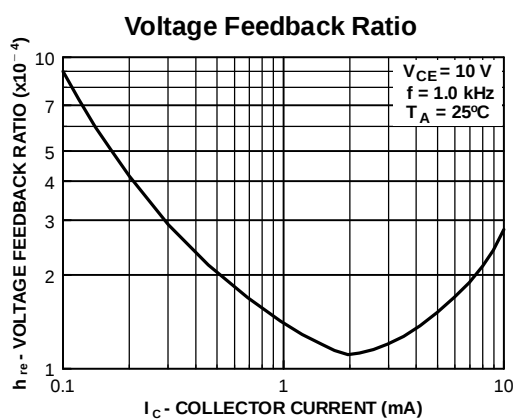
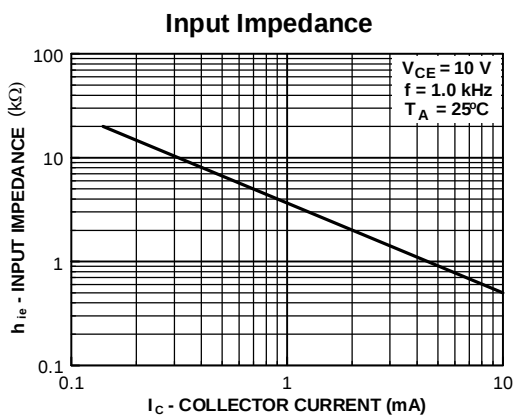
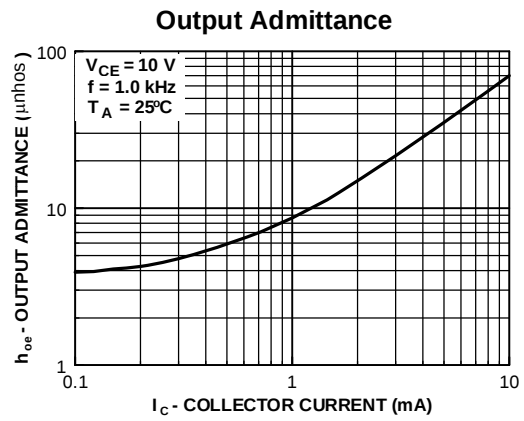
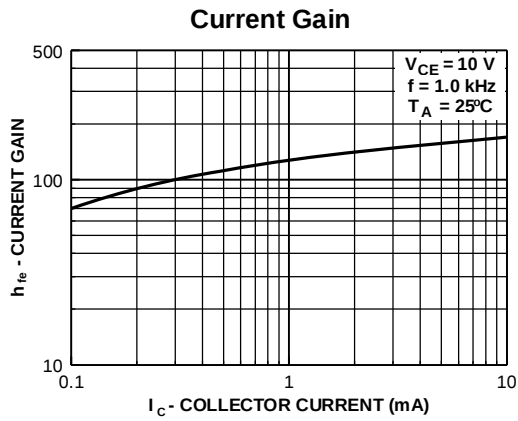
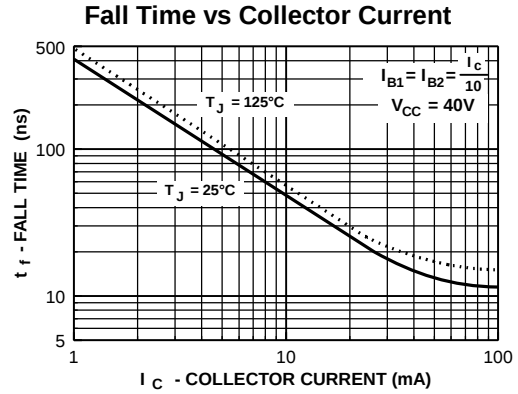
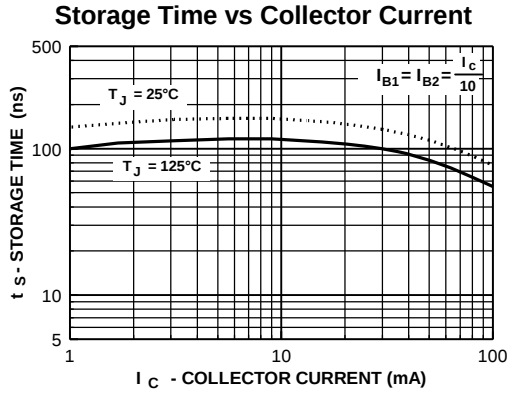
Turn-On Time vs Collector Current



Rise Time vs Collector Current



Typical Performance Characteristics (continued)



Test Circuits

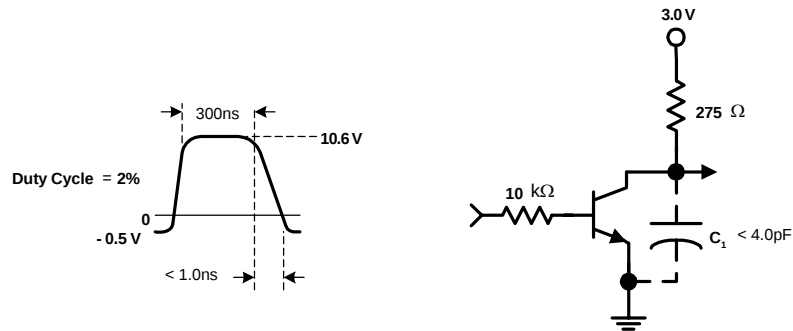


FIGURE 1: Delay and Rise Time Equivalent Test Circuit

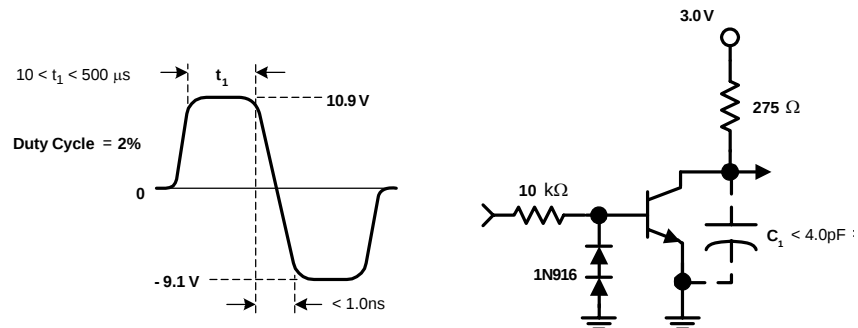


FIGURE 2: Storage and Fall Time Equivalent Test Circuit



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